



DESCRIPTION

The 1N4148W is available in SOD-123 Package.

FEATURES

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance
- Available in SOD-123 Package

ORDERING INFORMATION

Package Type	Part Number			
SOD-123	1N4148W			
Note	3,000pcs/Reel			
AiT provides all RoHS Compliant Products				

MECHANICAL DATA

- Case: SOD-123, Molded Plastic
- Terminals: Soldera ble per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Code only or Date Code and Type Code: T4
- Weight: 0.01 grams (approx.)

PIN DESCRIPTION



Equivalent Circuit Diagram





ABSOLUTE MAXIMUM RATINGS

$@T_A = 25^{\circ}C$ unless otherwise specified	
V _{RM} , Non-Repetitive Peak Reverse Voltage	100V
V _{RRM} , Peak Repetitive Reverse Voltage	75V
V _{RWM,} Working Peak Reverse Voltage	75V
V _R , DC Blocking Voltage	75V
V _{R(RMS)} , RMS Reverse Voltage	53V
IFM, Forward Continuous Current NOTE1	
Io, Average Rectified Output Current NOTE1	150mA
IFSM, Non-Repetitive Peak Forward Surge Current	
@t = 1.0µs	2.0 A
@t = 1.0s	1.0 A
Pd, Power Dissipation NOTE1	350mW
$R_{\theta JA}$, Thermal Resistance Junction to Ambient Air NOTE1	357K/W
T _J , T _{STG} , Operating and Storage Temperature Range	-65°C to +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Valid provided that terminals are kept at ambient temperature.



ELECTRICAL CHARACTERISTICS

T_A = 25°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Max	Unit	
Maximum Forward Voltage	Vfm	I _F = 1.0mA	-	0.715	V	
		I _F = 10mA	-	0.855		
		I⊧ = 50mA	-	1.0	v	
		l⊧ = 150mA	-	1.25		
Maximum Peak Reverse Current	Irm	V _R = 75V	-	1.0	μΑ	
		V _R = 75V, T _J = 150°C	-	50		
		V _R = 25V, T _J = 150°C	-	30		
		V _R = 20V	-	25	nA	
Junction Capacitance	CJ	V _R = 0, f = 1.0MHz	-	2.0	pF	
	t _{rr}	$I_{\rm F} = I_{\rm R} = 10 {\rm mA},$		4.0	ns	
Reverse Recovery Time		$I_{rr} = 0.1 \text{ x } I_{R}, R_{L} = 100 \Omega$	-			



TYPICAL CHARACTERISTICS

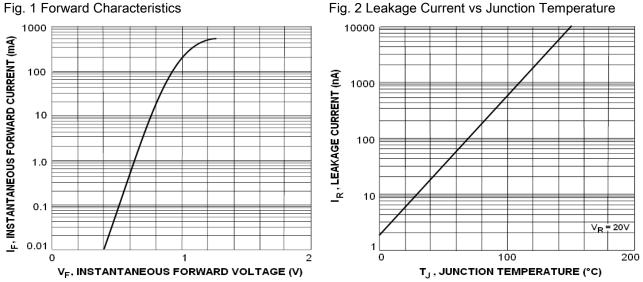
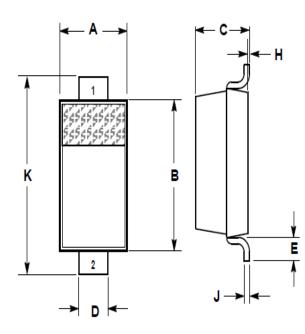


Fig. 2 Leakage Current vs Junction Temperature

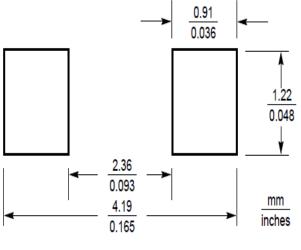


PACKAGE INFORMATION

Dimension in SOD-123 Package (Unit: mm)



RECOMMENDED FOOTPRINT FOR SOD-123





DIM	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
А	0.055	0.071	1.40	1.80	
В	0.100	0.112	2.55	2.85	
С	0.037	0.053	0.95	1.35	
D	0.020	0.028	0.50	0.70	
E	0.004	-	0.25	-	
Н	0.000	0.004	0.00	0.10	
J	-	0.006	-	0.15	
К	0.140	0.152	3.55	3.85	



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